TOSHIBA Field Effect Transistor Silicon N Channel MOS Type ( $\pi$ -MOSVII)

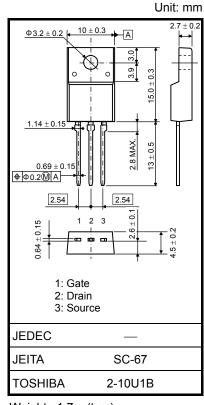
# **TK19A45D**

#### Switching Regulator Applications

- Low drain-source ON-resistance: RDS (ON) = 0.19  $\Omega$  (typ.)
- High forward transfer admittance:  $|Y_{fs}| = 10 \text{ S}$  (typ.)
- Low leakage current:  $I_{DSS} = 10 \ \mu A \ (max) \ (V_{DS} = 450 \ V)$
- Enhancement-mode:  $V_{th} = 2.0$  to 4.0 V ( $V_{DS} = 10 \text{ V}$ ,  $I_D = 1 \text{ mA}$ )

Characteristics		Symbol	Rating	Unit
Drain-source voltage		V <sub>DSS</sub>	450	V
Gate-source voltage		V <sub>GSS</sub>	±30	V
Drain current	DC (Note 1)	۱ <sub>D</sub>	19	
	Pulse (t = 1 ms) (Note 1)	I <sub>DP</sub>	76	A
Drain power dissipation (Tc = $25^{\circ}$ C)		PD	50	W
Single pulse avalanche energy (Note 2)		E <sub>AS</sub>	513	mJ
Avalanche current		I <sub>AR</sub>	19	А
Repetitive avalanche energy (Note 3)		E <sub>AR</sub>	5.0	mJ
Channel temperature		T <sub>ch</sub>	150	°C
Storage temperature range		T <sub>stg</sub>	-55 to 150	°C





Weight : 1.7 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

#### **Thermal Characteristics**

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	R <sub>th (ch-c)</sub>	2.5	°C/W
Thermal resistance, channel to ambient	R <sub>th (ch-a)</sub>	62.5	°C/W

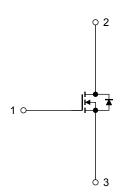
Note 1: Please use devices on conditions that the channel temperature is below 150°C.

Note 2:  $V_{DD}$  = 90 V,  $T_{ch}$  = 25°C (initial), L = 2.37 mH, R<sub>G</sub> = 25  $\Omega$ , I<sub>AR</sub> = 19 A

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic sensitive device. Please handle with caution.

#### Internal Connection



Start of commercial production 2009-08

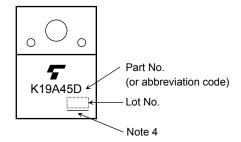
**Electrical Characteristics (Ta = 25°C)** 

Char	acteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cu	rrent	I <sub>GSS</sub>	$V_{GS}=\pm 30~V,~V_{DS}=0~V$	_		±1	μA
Drain cut-off curr	rent	I <sub>DSS</sub>	$V_{DS} = 450 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$	_		10	μA
Drain-source bre	akdown voltage	V (BR) DSS	$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$	450		_	V
Gate threshold v	oltage	V <sub>th</sub>	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 1 \text{ mA}$	2.0		4.0	V
Drain-source ON	l-resistance	R <sub>DS (ON)</sub>	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 9.5 \text{ A}$	_	0.19	0.25	Ω
Forward transfer	admittance	Y <sub>fs</sub>	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 9.5 \text{ A}$	2.4	10	_	S
Input capacitance	e	C <sub>iss</sub>		—	2600		
Reverse transfer capacitance		C <sub>rss</sub>	$V_{DS} = 25 V, V_{GS} = 0 V, f = 1 MHz$	_	11	_	pF
Output capacitance		C <sub>oss</sub>			280		
Switching time	Rise time	tr	$\begin{array}{c} 10 \text{ V} \\ \text{V}_{GS} \\ 0 \text{ V} \\ 50 \Omega \end{array} \begin{array}{c} \text{I}_{D} = 9.5 \text{ A} \text{ V}_{OUT} \\ \text{V}_{OT} \\ \text{V}_{DD} \approx 200 \text{ V} \end{array}$		50		
	Turn-on time	t <sub>on</sub>			100		ns
	Fall time	t <sub>f</sub>			25	_	. 113
	Turn-off time	t <sub>off</sub>			150	_	
Total gate charge		Qg			45		
Gate-source charge		Q <sub>gs</sub>	$V_{DD}\approx 360$ V, $V_{GS}$ = 10 V, $I_{D}$ = 19 A		28		nC
Gate-drain charge		Q <sub>gd</sub>	]	_	17	—	

#### Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I <sub>DR</sub>	—	_	_	19	А
Pulse drain reverse current (Note 1)	I <sub>DRP</sub>	_	_	_	76	А
Forward voltage (diode)	V <sub>DSF</sub>	$I_{DR} = 19 \text{ A}, V_{GS} = 0 \text{ V}$	_	_	-1.7	V
Reverse recovery time	t <sub>rr</sub>	$I_{DR} = 19 \text{ A}, V_{GS} = 0 \text{ V},$	_	1700	_	ns
Reverse recovery charge	Q <sub>rr</sub>	dI <sub>DR</sub> /dt = 100 A/μs	_	25	_	μC

#### Marking



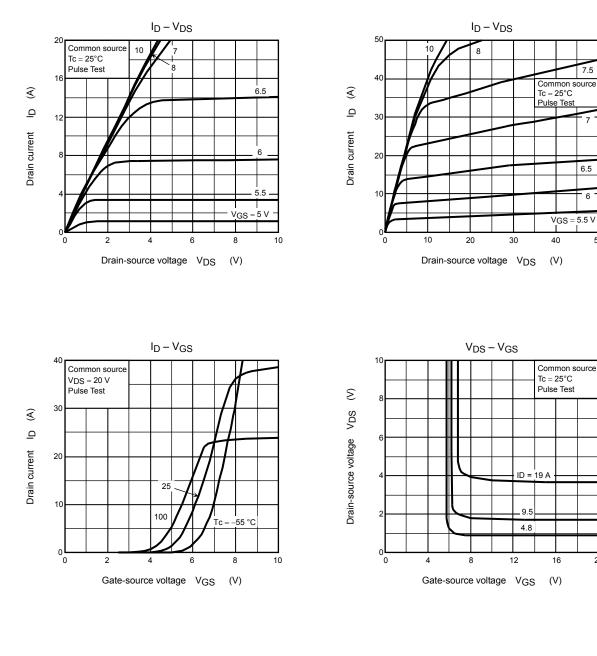
Note 4 : A line under a Lot No. identifies the indication of product Labels [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

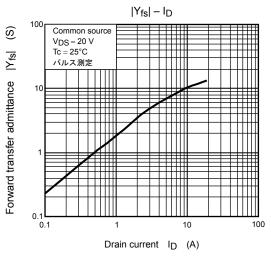
Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

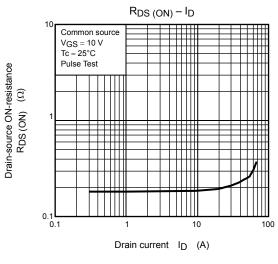
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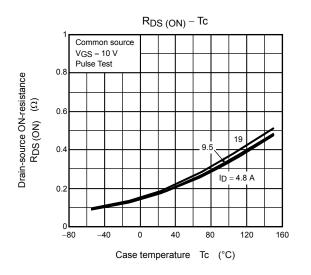
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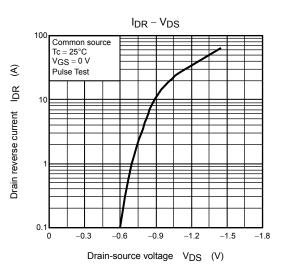


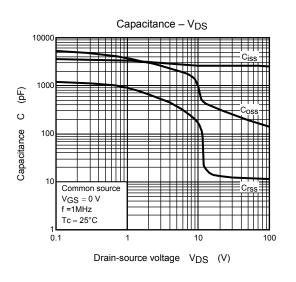


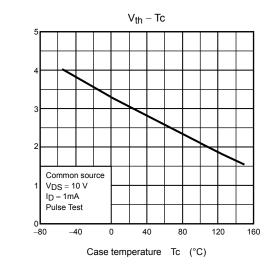


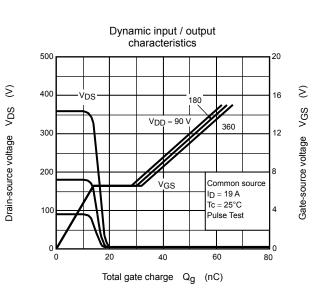
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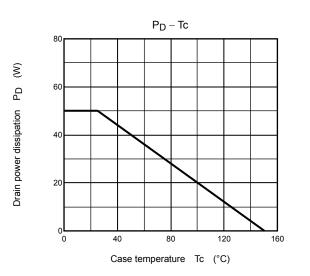






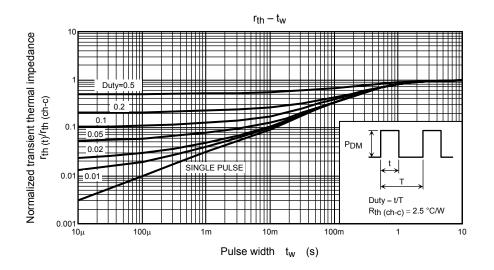




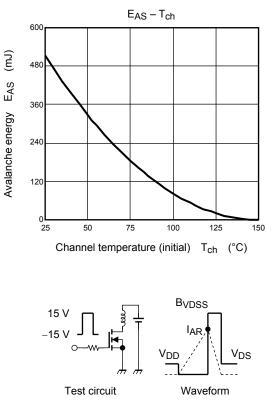


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Gate threshold voltage



SAFE OPERATING AREA 100 ID max (pulse) 100 μs D max (continuous) 1 ms ' 10 € +++++++ DC operation Tc = 25°C ₽ Drain current 0.1 0.01 ※ Single pulse Tc=25°C Curves must be derated linearly with increase in VDSS max temperature. 0.001 0.1 10 100 1000 Drain-source voltage  $V_{DS}$  (V)



$R_{G} = 25 \Omega$	$E_{AS} = \frac{1}{2} \cdot L \cdot l^2 \cdot ($	$\left(\frac{BVDSS}{BVDSS}-VDD\right)$
$V_{DD} = 90 \text{ V}, \text{ L} = 2.37 \text{ mH}$	2 (	BVDSS-VDD

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